

## **Standard Rectifier**

 $V_{RRM} = 1600 V$ 

 $I_{\text{FAV}} = 2x \quad 60 \text{ A}$ 

 $V_{\rm F} = 1.22 \, \rm V$ 

### Parallel legs

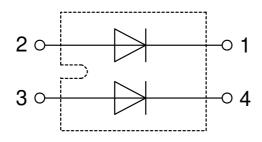
Part number

#### DSI2x55-16A



Backside: isolated





#### Features / Advantages:

- Planar passivated chips
- Very low leakage currentVery low forward voltage drop
- Improved thermal behaviour

#### **Applications:**

- Diode for main rectification
- For single and three phase bridge configurations

Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper
- internally DCB isolated
  Advanced power cycling

#### **Disclaimer Notice**

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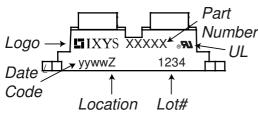


Rectifier			Ratings				
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse bloc	cking voltage	$T_{VJ} = 25^{\circ}C$			1700	V
V <sub>RRM</sub>	max. repetitive reverse blocking	voltage	$T_{VJ} = 25^{\circ}C$			1600	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1600 V	$T_{VJ} = 25^{\circ}C$			100	μΑ
		$V_R = 1600 V$	$T_{VJ} = 150$ °C			1.5	mΑ
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 55 A	$T_{VJ} = 25^{\circ}C$			1.26	V
		$I_{F} = 110 \text{ A}$				1.54	٧
		I <sub>F</sub> = 55 A	T <sub>VJ</sub> = 125°C			1.22	٧
		$I_F = 110 \text{ A}$				1.58	٧
I FAV	average forward current	T <sub>c</sub> = 95°C	T <sub>vJ</sub> = 150°C			60	Α
		rectangular d = 0.5					
V <sub>F0</sub>	threshold voltage		T <sub>vJ</sub> = 150°C			0.83	V
r <sub>F</sub>	slope resistance } for power	loss calculation only				6.2	mΩ
R <sub>thJC</sub>	thermal resistance junction to ca	ase				0.6	K/W
R <sub>thCH</sub>	thermal resistance case to heat	sink			0.1		K/W
P <sub>tot</sub>	total power dissipation		$T_{C} = 25^{\circ}C$			210	W
I <sub>FSM</sub>	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			800	Α
		t = 8.3  ms; (60 Hz), sine	$V_R = 0 V$			865	Α
		t = 10 ms; (50 Hz), sine	T <sub>vJ</sub> = 150°C			680	Α
		t = 8,3  ms; (60 Hz), sine	$V_R = 0 V$			735	Α
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			3.20	kA2s
		t = 8.3  ms; (60 Hz), sine	$V_R = 0 V$			3.12	kA2s
		t = 10 ms; (50 Hz), sine	T <sub>vJ</sub> = 150°C			2.31	kA2s
		t = 8,3  ms; (60 Hz), sine	$V_R = 0 V$			2.25	kA2s
CJ	junction capacitance	$V_{R} = 400 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		25		pF



Package SOT-227B (minibloc)				Ratings				
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per terminal					150	Α
T <sub>VJ</sub>	virtual junction temperatur	e			-40		150	°C
T <sub>op</sub>	operation temperature				-40		125	°C
T <sub>stg</sub>	storage temperature				-40		150	°C
Weight						30		g
M <sub>D</sub>	mounting torque				1.1		1.5	Nm
$\mathbf{M}_{_{T}}$	terminal torque				1.1		1.5	Nm
d <sub>Spp/App</sub>	oroonaga diatanaa an aurt	inco Latrikina diatanoa through air	terminal to terminal	10.5	3.2			mm
d <sub>Spb/Apb</sub>	creepage distance on sun	ace   striking distance through air	terminal to backside	8.6	6.8			mm
V <sub>ISOL</sub>	isolation voltage	t = 1 second	50/60 Hz. RMS: lisoL ≤ 1 mA		3000			٧
		t = 1 minute			2500			٧

# **Product Marking**



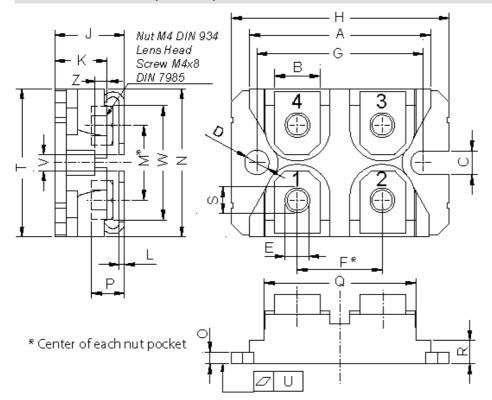
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSI2x55-16A	DSI2x55-16A	Tube	10	483699

Similar Part	Package	Voltage class
DSI2x55-12A	SOT-227B (minibloc)	1200

Equiva	lent Circuits for	Simulation	* on die level	$T_{VJ} = 150$ °C
$I \rightarrow V_0$	)—[R <sub>0</sub> ]-	Rectifier		
V <sub>0 max</sub>	threshold voltage	0.83		V
$R_{0 max}$	slope resistance *	4.3		$m\Omega$



### Outlines SOT-227B (minibloc)



Dim.	Millir	Millimeter		hes
DIIII.	min	max	min	max
Α	31.50	31.88	1.240	1.255
В	7.80	8.20	0.307	0.323
С	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
Е	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
Н	37.80	38.23	1.488	1.505
J	11.68	12.22	0.460	0.481
Κ	8.92	9.60	0.351	0.378
L	0.74	0.84	0.029	0.033
M	12.50	13.10	0.492	0.516
N	25.15	25.42	0.990	1.001
0	1.95	2.13	0.077	0.084
Р	4.95	6.20	0.195	0.244
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.167
S	4.55	4.85	0.179	0.191
Т	24.59	25.25	0.968	0.994
U	-0.05	0.10	-0.002	0.004
V	3.20	5.50	0.126	0.217
W	19.81	21.08	0.780	0.830
Ζ	2.50	2.70	0.098	0.106

